

TP Type High Precision and Low G-Sensitivity 3.2 x 2.5 mm SMD Voltage Controlled Temperature Compensated Crystal Oscillator

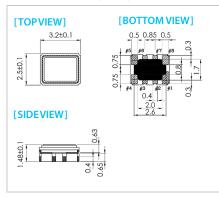
FEATURES

- Typical 3.2 x 2.5 x 1.48 mm ceramic SMD package.
- Stratum 3 (Overall ±4.6ppm including 20 years aging.)
- Low G Sensitivity: < 0. 5ppb/g
- CMOS and Clipped Sine wave (without DC-cut capacitor) output optional.

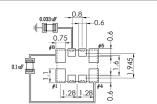
TYPICAL APPLICATION

- Stratum 3
- Femtocell, Base Stations

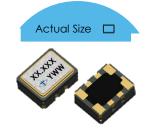
DIMENSION (mm)



SOLDER PAD LAYOUT (mm)



Recommended Soldering Pattern To ensure optimal oscillator performance, place a by-pass capacitor of 0.1 μ F as close to the part as possible between V_{DD} and GND Pads.



RoHS Compliant

PIN FUNCTION (mm)

PIN#	FUNCTION				
1	V _{CON} :VC-TCXO				
	NC:TCXO				
2	Do not Connect				
3	Do not Connect				
4	GND				
5	Output				
6	Tri-State				
7	Filter				
8	V _{DD}				

ELECTRICAL SPECIFICATION

Parameter		2.5V / 3.3V					
		Min.	Тур.	Max.	Unit	Test Condition	
Supply Voltage Variation (VDD)			V _{DD} – 5%		V _{DD} + 5%	V	
Frequency Range		5		52	MHz		
Standard Frequency		20, 25, 40			MHz	Standard frequencies are frequencies which the crystal has been designed and does not imply a stock position.	
Operating Temp. Range		-20 ~ +70, -40 ~ +85			°C		
Frequency Stability (Overall, 20 Years)					±4.6	ppm	Including calibration @ 25°C, supply voltage $V_{DD}\pm5\%$, load $\pm10\%$, reflow soldering, 20 years aging and frequency stability over temperature.
Frequency Stability Vs Temp. Range				±0.1 (-20~+70°C) ±0.2 (-40~+85°C)	ppm	Ref. to (FMAX+Fmin)/2	
Holdover Stability				0.37	ppm	Including 24hours aging , supply voltage V _{DD} ±5% and frequency stability over temperature.	
Supply Current	CMOS				7.5	mA	
	Clipped Sine Wave				5	mA	
Output Level		Output High (Logic "1")	90%V _{DD}			V	
	CMOS	Output Low (Logic "0")			10%V _{DD}	V	
		Duty	45		55	%	
	Clipped Sine Wave		0.8			Vp-p	
Load	CMOS			15pF			
	Clipped Sine Wave			10 KΩ // 10pF			
Phase Noise @ 10MHz	@ 100Hz				-130	dBc/Hz	Please add filter capacitor as suggested, and 33nF at pin7
	@ 1kHz				-145	dBc/Hz	
	@ 10kHz				-154	dBc/Hz	
G Sensitivity			0.3	0.5	ppb/G	Г, 20-2000Hz	
Start Time				5	mSec		
Storage Temp. Range		-55		+125	°C		
VCTCXO	Control Voltage Range		0.5		2.5	V	
	Pulling Range		±5.0			ppm	
	Vc Input Impedance		100			kΩ	

Note: not all combination of options are available. Other specifications may be available upon request.

Specifications subject to change without notice.